AD178A Datasheet

Zhuhai Jieli Technology Co.,LTD

Version: 1.1

Date: 2023.09.28



AD178A Features

CPU

- 32bit DSP
- Maximum speed 160MHz
- Interrupts with 8 priority level

Memory

Optional built-in flash memory

Clocks

- On-chip 16 MHz clock
- On-chip 200KHz lower-temperature-drift clock

Audio APA

- Support for driving 4 or 8 ohm speaker
- Mono Class-D Speaker Amplifier
 - 0.42W/8 Ω @3.7V
 - $0.17W/8 \Omega @2.4V$
 - 0.62W/4 Ω @3.7V
 - 0.25W/4 Ω @2.4V

Peripherals

- Three multi-function 16-bit timers, support capture and PWM mode
- Two UART Controllers(UART0/1) supports DMA and Flow Control

- One IIC Master controller
- One SPI Master / Slaver controller with DMA
- 2-channel 10-bit general purpose ADC
- 4-channel Advance PWM controller
- 4 Individually programmable and multiplexed GPIO pins
- Digital peripheral crossbar
- Support Touch Key of pulse counter
- Up to 4 external interrupt / wake-up source (low power available,can be multiplexed to any I/O)
- Watchdog

PMI

- Less than 2uA soft off current
- VBAT range : 2.0V to 5.5V
- IOVDD range: 2.0V to 3.4V

Packages

SOP8

Temperature

- Operating temperature: -40° C to $+85^{\circ}$ C
- Storage temperature: -65° C to $+150^{\circ}$ C

Applications

- Sound Toy
- Audio player



1 Block Diagram

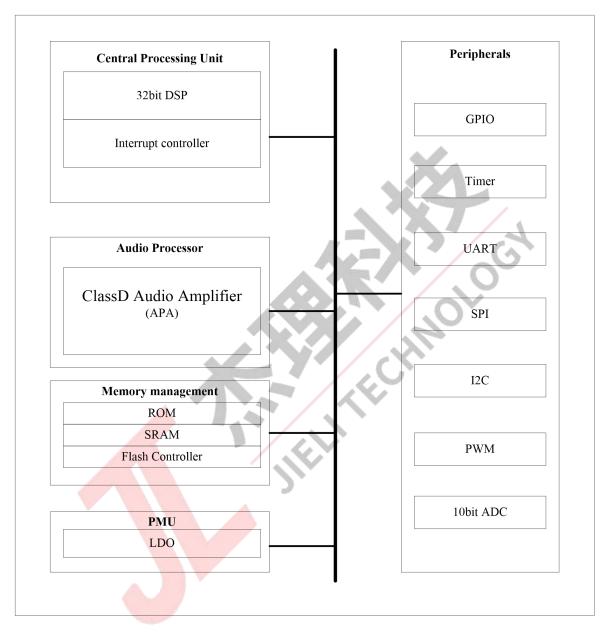


Figure 1-1 AD178A Block Diagram



2 Pin Definition

2.1 Pin Assignment

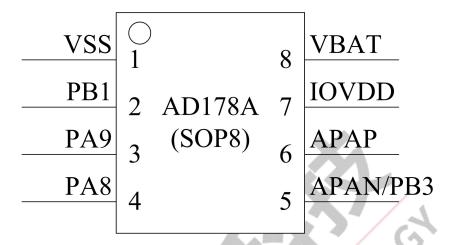


Figure 2-1 AD178A Package Diagram





2.2 Pin Description

Table 2-1 AD178A Pin Description

PIN NO.	Name	Туре	Function	Other Function		
1	VSS	G		System ground;		
2	PB1	I/O	5V tolerant IO	Serial port code upgrade pin;		
3	PA9	I/O	GPIO (pull down)	ADC9:ADC Input Channel 9;		
4	PA8	I/O	GPIO (pull down)	ADC8:ADC Input Channel 8;		
-	PB3	I/O	5V tolerant IO			
5	APAN	0		Class-D APA Negative Output;		
6	APAP	0		Class-D APA Positive Output;		
7	IOVDD	РО	Power supply for GPIO	Built-in linear voltage regulator output;		
8	VBAT	PI		Power supply input;		

Pin Type	Description	Pin Type	Description
P	Power	I/O	Input or Output
PI	Power Input	i	Input
PO	Power Output	0	Output
AO	Analog Output	G	Ground

CROSSBAR							
SPI0	SPI1	IIC	UART0	UART1	PWMCH0	PWMCH1	
SPI0_CLK	SPI1_CLK	IIC_CLK	UART0_TX	UART1_TX	PWMCH0L	PWMCH1L	
SPI0_DI	SPI1_DI	IIC_DAT	UART0_RX	UART1_RX	PWMCH0H	PWMCH1H	
SP0_D0	SPI1_D0						
SP0_DAT2							
SP0_DAT3		/					

	Input Channel x6		Output Channel x8			
WAKEUP	Timer1	IRFLT	PWM1	CLK_OUT0	APA_DOP	
PWMFP0	Timer2	TOUCH_CAP	PWM2	CLK_OUT1	APA_DON	
PWMFP1	CAP1	UART1_CTS	UART1_RTS	CLK_OUT2		
EXT_CLK	CAP2					



3 Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	6	V
$V_{\rm IOVDD}$	Voltage applied at IOVDD	-0.3	3.6	V
$ m V_{GPIO}$	Voltage applied to GPIO	-0.3	IOVDD+0.3	V
$V_{ m HVIO}$	Voltage applied to High Voltage Resistant IO	-0.3	+5.5	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

3.2 ESD Protectio

Table 3-2

Parameter	Тур.	Test pin	Reference standard	
Human Body Mode	±4KV	All pins	JEDEC EIA/JESD22-A114	
Machine Mode	±200V	All pins	JEDEC EIA/JESD22-A115	
Charge Device Model	±2KV	All pins	JEDEC EIA/JESD22-C101F	
I otolo vie	±200mA	All GPIO pins	JEDEC STANDARD NO.78E	
Latch up	1.5xVopmax	All power pins	JEDEC STANDARD NO./8E	

Note: 1.5xVopmax = 1.5 times maximum operating voltage.

3.3 PMU Characteristics

Table 3-3

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
VBAT	Voltage Input	2.0	3.7	5.5	V	_
IONDD	Voltage output	2.0	3.0	3.4	V	VBAT = 4.2V, 10mA loading
IOVDD	Loading current	_	_	100	mA	IOVDD=3.3V@VBAT ≥ 3.6V
V_{LVD}	Voltage input	1.8	2.5	2.5	V	Low-Voltage Detection of IOVDD



3.4 IO Input/Output Electrical Logical Characteristics

Table 3-4

GPIO input ch	GPIO input characteristics									
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions				
$ m V_{IL}$	Low-Level Input Voltage	-0.3	1	0.3* IOVDD	V	IOVDD = 3.0V				
$ m V_{IH}$	High-Level Input Voltage	0.7* IOVDD	-	IOVDD+0.3	V	IOVDD = 3.0V				
High Voltage R	Resistant IO input chara	ecteristics								
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions				
V _{IL}	Low-Level Input Voltage	-0.3	_	0.3* IOVDD	V	IOVDD = 3.0V				
$ m V_{IH}$	High-Level Input Voltage	0.7* IOVDD	1	+5V	V	IOVDD = 3.0V				
Resistant IO ou	utput characteristics									
Symbol	Paramete	er	GPIO	Тур	Unit	Test Conditions				
$ m V_{OL}$	0.1*IOVDD Driv	e current	PA8,PA9 PB1,PB3	HD=1:-7 HD=2:-22 HD=3:-27	mA	IOVDD = 3.0V				
	0.1*HPVDD Driv APA IO total current l		APAN APAP	-200		VBAT=3.7V				
$ m V_{OH}$	0.9*IOVDD Driv	PA8,PA9	HD=1:7 HD=2:24 HD=3:56	mA	IOVDD = 3.0V					
	0.9*HPVDD Driv		PB1,PB3 APAN APAP	7 200		VBAT=3.7V				

3.5 Internal Resistor Characteristics

Table 3-5

Port	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA8,PA9,PB1,PB3	10K	200K	 PA8~PA9 default pull down Internal pull-up/pull-down resistance accuracy ±20%



3.6 Audio APA Characteristics

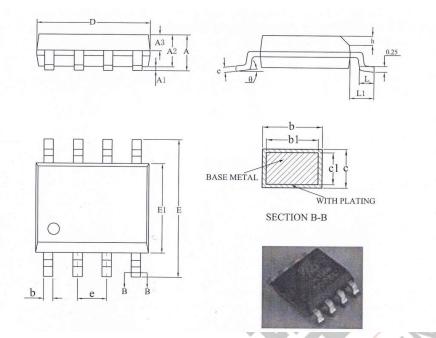
Table 3-6

_	270	3.50	Table 3-6				~	
Parameter	MODE	Min	Тур	Max	Unit	Test Conditions		
Frequency Response		20	_	20K	Hz	R _L =10K	,VBAT=3.7V	
		_	1.57		Vrms	$R_L=4\Omega$		
	Diff (N to P)	_	1.83	_	Vrms	$R_L=8\Omega$	f=1kHz/0dB	
		_	2.22	_	Vrms	R _L =10K	VBAT=3.7V	
Output Swing	Single-ended	_	1.11	_	Vrms	$R_L=10K$		
output 5 ming		_	0.99	_	Vrms	$R_L=4\Omega$		
	Diff (N to P)	_	1.17		Vrms	$R_L=8\Omega$	f=1kHz/0dB	
		_	1.44		Vrms	R _L =10K	VBAT=2.4V	
	Single-ended	_	0.72	4	Vrms	R _L =10K		
		_	0.62		W	$R_L=4\Omega$	f=1kHz/0dB	
Output power	Diff (N to P)	_	0.42	4	W	$R_L=8\Omega$	VBAT=3.7V	
Output power	DIII (IV to 1)	_	0.25		W	$R_L=4\Omega$	f=1kHz/0dB	
		_	0.17	/ _ \	W	$R_L=8\Omega$	VBAT=2.4V	
		_	-31	_	dB	$R_L=4\Omega$	f=1kHz/0dB	
	Diff (N to P)	_	-35		dB	$R_L=8\Omega$	A-Weighted	
		_	-75		dB	R _L =10K	VBAT=3.7V	
THD+N	Single-ended		-70	X	dB	R _L =10K	VDA1-3./V	
THD+N			-31)	dB	$R_L=4\Omega$	f=1kHz/0dB A-Weighted	
	Diff (N to P)		-36	_	dB	$R_L=8\Omega$		
			-73	_	dB	R _L =10K	_	
	Single-ended	-	-70	_	dB	R _L =10K	VBAT=2.4V	
		_	97	_	dB	$R_L=4\Omega$	f=1kHz/0dB	
	Diff (N to P)	_	97	_	dB	$R_L=8\Omega$		
		_	95	_	dB	R _L =10K	A-Weighted VBAT=3.7V	
S/N	Single-ended		75	_	dB	R _L =10K	V DA1-3./V	
5/IN	1 1 1 1	_	94	_	dB	$R_L=4\Omega$	£_11,11,-/0,1D	
	Diff (N to P)	_	94	_	dB	$R_L=8\Omega$	f=1kHz/0dB	
		_	88	_	dB	R _L =10K	A-Weighted VBAT=2.4V	
	Single-ended	_	72	_	dB	R _L =10K	V DA1-2.4 V	
		_	88	_	dB	$R_L=4\Omega$	C 11 II / (0 1D	
	Diff (N to P)	_	88	_	dB	$R_L=8\Omega$	f=1kHz/-60dB	
		_	86	_	dB	R _L =10K	A-Weighted	
Daw i B	Single-ended	_	75	_	dB	R _L =10K	VBAT=3.7V	
Dynamic Range		_	87	_	dB	$R_L=4\Omega$	C 11 II / 60 IP	
	Diff (N to P)	_	87	_	dB	$R_L=8\Omega$	f=1kHz/-60dB	
		_	85		dB	R _L =10K	A-Weighted	
	Single-ended	_	74	_	dB	R _L =10K	VBAT=2.4V	



4 Package Information

4.1 SOP8

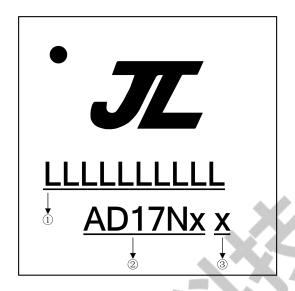


SYMBOL	M	ILLIMET	ER
SIMBOL	MIN	NOM	MAX
A	_	_	1.75
A1	0.10	_	0.225
A2	1.30	1.40	1.50
A3	0.60	0.65	0.70
b	0.39	_	0.47
b1	0.38	0.41	0.44
c	0.20	_	0.24
c1	0.19	0.20	0.21
D	4.80	4.90	5.00
Е	5.80	6.00	6.20
E1	3.80	3.90	4.00
e		1.27BSC	
h	0.25	_	0.50
L	0.50	_	0.80
Ll		1.05REF	
θ	0	25122	8°

Figure 4-1 AD178A Package



5 IC Marking Information



- ① LLLLLLLLL: Production Batch
- ② AD17Nx: Chip Model
- 3 Built-in flash size
 - 0: No Flash Memory
 - 2: 2Mbit Flash
 - 4: 4Mbit Flash
 - 8: 8Mbit Flash
 - 6: 16Mbit Flash
 - 3: 32Mbit Flash



6 Solder-Reflow Condition

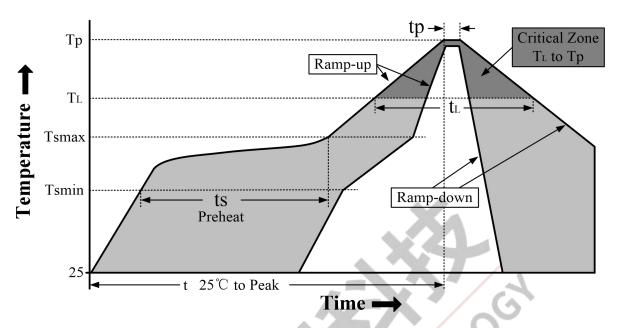


Figure 6-1 Classification Reflow Profile

Classification Profiles

Table 6-1

	Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
	Temperature Min (T _{smin})	100 °C	150 ℃
Preheat/	Temperature Max (T _{smax})	150 °C	200 ℃
Soak	Time (ts) from (T _{smin} to T _{sma} x)	60-120 seconds	60-180 seconds
Average ra	amp-up rate $(T_{smax} \text{ to } T_p)$	3 °C/second max	3 °C/second max
Liquidous temperature (T _L)		183 ℃	217 ℃
Time (t _L) 1	maintained above T _L	60-150 seconds	60-150 seconds
Peak pack	age body temperature (Tp)	See Table 6-2.	See Table 6-3.
Time within 5°C of actual Peak Temperature (tp)		10-30 seconds	20-40 seconds
Ramp-down rate (T _p to T _L)		6 °C/second max.	6 °C/second max.
Time 25	C to peak temperature	6 minutes max.	8 minutes max.

Note 1: All temperatures refer to topside of the package, measured on the package body surface.

Note 2: Time within 5° C of actual peak temperature (tp) specified for the reflow profiles is a "supplier" minimum and "user" maximum.

SnPb - Classification Temperature

Table 6-2

Package	Volume mm ³	Volume mm ³
Thickness	< 350	≥ 350
<2.5 mm	240 +0/-5 °C	225 +0/-5 °C
≥ 2.5 mm	225 +0/-5 °C	225 +0/-5 °C



Pb-free - Classification Temperature Table 6-3

Package	Volume mm ³	Volume mm ³	Volume mm ³
Thickness	< 350	350 - 2000	> 2000
< 1.6mm	260 ℃	260 ℃	260 °C
1.6 mm - 2.5mm	260 ℃	250 ℃	245 ℃
> 2.5mm	250 °C	245 ℃	245 ℃





7 Revision History

Date	Revision	Description
2023.07.13	V1.0	Initial Release.
2023.09.28	V1.1	Update Pin Definition. Update Features modification.

